USA Model (former and new types) E Model AFP Model



INTEGRATED STEREO AMPLIFIER

100 W (8 Ω)

5 Hz - 70 kHz

90W (4Ω)

SPECIFICATIONS

GENERAL

System:

Power amplifier section: direct-coupled pure complementary symmetry circuitry

Preamplifier: circuitry

direct-coupled two-stage phono, flat and negative feed-back control

Power Requirements:

120 V ac, 60 Hz (USA model) 110, 127, 220 or 240 V ac, 50/60 Hz,

adjustable (AEP, model) 100, 120, 220 or 240 V ac, 50/60 Hz, adjustable (E model) 270W (by IEC Standard)

Power Consumption:

Dimensions:

approx

prox. 460(w) x 168(h) x 323(d) mm, 18½ x 65½ x 12¾ inches (AEP model) 430(w) x 168(h) x 323(d) mm, 16½ x 65½ x 12¾ inches (E, USA model) including projecting parts and controls

Weight:

annrox

prox. 12.4 kg, 27 lb 5 oz (AEP model) in net 11.5 kg, 25 lb 6 oz (E, USA model) 15.2 kg, 33 lb 8 oz with shipping carton (AEP model)

13.6 kg, 30 lb (E, USA model)

POWER AMPLIFIER SECTION

Continuous RMS Power Output: (less than 0.1% THD, both channels driven simultaneously)

at 1 kHz

35 + 35 W (8 Ω) 30 + 30 W (4 \O) at 20 – 20,000 Hz 30 + 30 W (8 Ω) according to DIN 45500 35 + 35 W Dynamic Power Output: (IHE constant power

supply method) Power Bandwidth

(IHF): Harmonic Distortion:

Intermodulation (IM) Distortion:

(60 Hz: 7 kHz = 4:1) Frequency Response:

(at 1W output) S/N ratio:

Residual Noise:

Damping Factor:

45 (8 Ω, at 1 kHz) Inputs: POWER INPUT

Outputs:

sensitivity 1 V RMS (for rated output)

input

impedance 50 kΩ SPEAKER terminals A, B

less than 0.1% at rated output

less than 0.05 % at 1 W output

less that 0.1% at rated output

less than 0.05 % at 1 W output

greater than 110 dB, short-circuited

2 Hz -- 100 kHz +0 dB

less than $0.005 \mu W$ (8 Ω)

accept speakers of 4 \Omega or more HEADPHONE jack accepts low-and high-impedance stereo headphones

(Continued on next page.)

SONY SERVICE MANUAL

PREAMPLIFIER SECTION

Harmonic Distortion: less than 0.05 % at rated output

Intermodulation (IM)

less than 0.05 % at rated output

Distortion: (60 Hz: 7 kHz = 4:1)

PHONO 1, 2 RIAA equalization ±0.5 dB

Frequency response:

THORN 1, 2 RIAA equalization ±0.5 dB TUNER AUX 1, 2 TAPE 1, 2 REC/PB (input) EXT ADPT 1, 2

(input)

Tone Controls:

BASS: ±10 dB at 50 Hz (TURNOVER 250 Hz) ±10 dB at 100 Hz (TURNOVER 500 Hz) TREBLE:

±10dB at 10kHz (TURNOVER 2.5kHz) ±10dB at 20kHz (TURNOVER 5kHz)

Filters: LOW:

6 dB/octave attenuation below 35 Hz 6 dB/octave attenuation above 6 kHz

Loudness Switch: +10 dB at 50 Hz +3 dB at 10 kHz (att. 30 dB)

1----

	Sensitivity	Impedance	Maximum input capability*	S/N (weighting network)
PHONO 1, 2	2,5 mV	50 kΩ	300 mV	greater than 70 dB (B)
AUX 1, 2 TAPE 1, 2 REC/PB (input) EXT ADPT 1, 2 (input)	150 mV	100 kΩ		greater than 90 dB (A)

^{*} The maximum input capability is measured at a 0.05 % harmonic distortion.

Outputs

	Output voltage	Impedance		
REC OUT 1, 2	150 mV	4.7 kΩ		
PRE OUTPUT	1 V	3kΩ		
REC/PB	17 mV	82 kΩ		
EXT ADPT 1, 2	150 mV	4.7 kΩ		

Specification Label:

USA model

SONY	INTEGRATED	STEREO	AMPLIFIER
	MODEL NO. T AC 120V SERIAL NO.	A-4650 60Hz	130 W
		MADE	T IN TADAM

AEP model

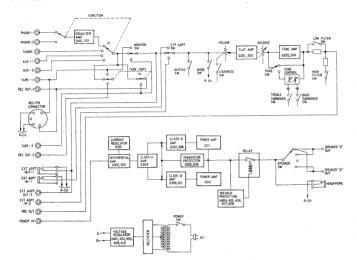
SONY®	INTEGRATED STEREO AMPLIFIER MODEL NO. TA -4650 AC IIO.127.220.240V ~ 50/60Hz 270W SERIAL NO.
	MADE IN JAPAN

E model

SONY INTEGRATED STEREO AMPLIFIER MODEL NO. TA = 4650 AC 100.120.220.240V 50/60Hz 270W SERIAL NO. MADE IN JAPAN

SECTION 1 OUTLINE

1-1. BLOCK DIAGRAM



SECTION 2 ADJUSTMENTS

Note: Turn POWER on and allow about three minutes for warm-up.

2-1. POWER SUPPLY VOLTAGE ADJUSTMENT

See Fig. 2-1 and 2-2.

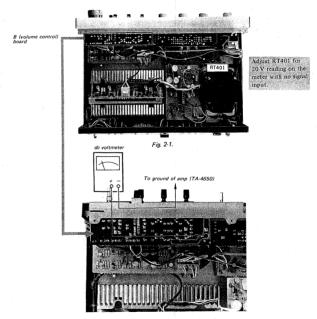


Fig. 2-2.

2-2. DC BIAS ADJUSTMENT

Adjust RT301 and RT351 for 75 mV reading on the meter with no signal input.

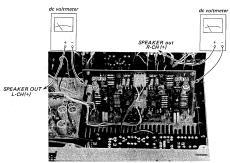
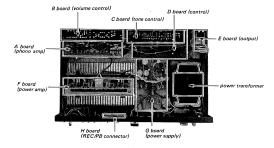


Fig. 2-3.

2-3. CHASSIS LAYOUT



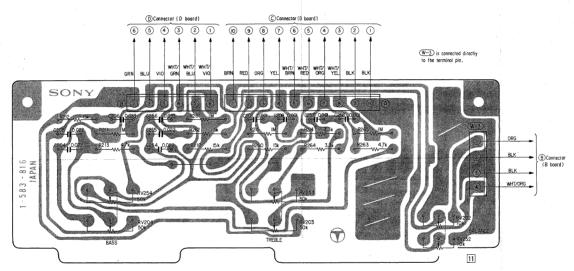
/EMO	 		 	

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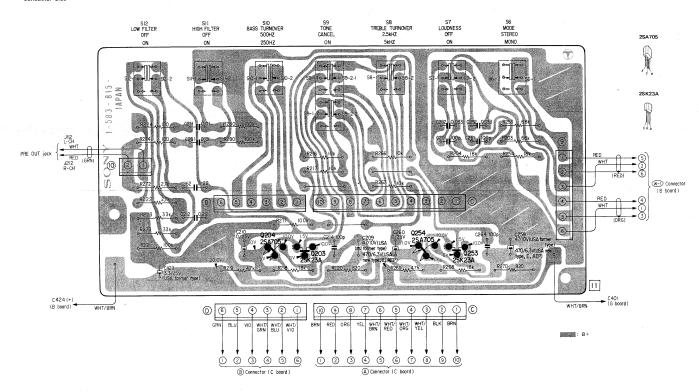
SECTION 3

3-1. MOUNTING DIAGRAM - C Board (tone control) -



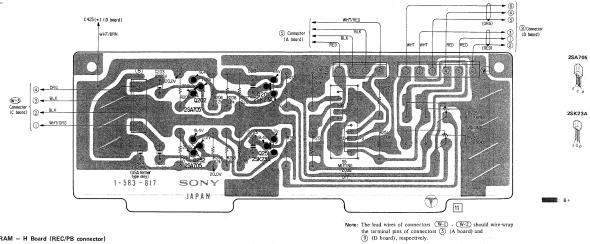
Note: The lead wires of connector $(\underline{W-3})$ should wire-wrap the terminal pins of connector $(\underline{3})$ on B board.

3-2. MOUNTING DIAGRAM - D Board (control) -

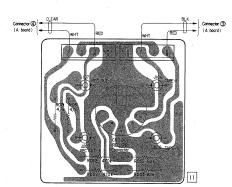


3-3. MOUNTING DIAGRAM - B Board (volume control) -

- Conductor Side -



3-4. MOUNTING DIAGRAM - H Board (REC/PB connector)

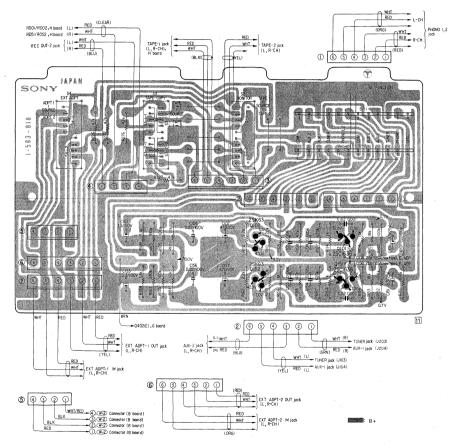


- 11 -

TA-4650 TA-4650

3-5. MOUNTING DIAGRAM - A Board (phono amp) -

- Conductor Side -

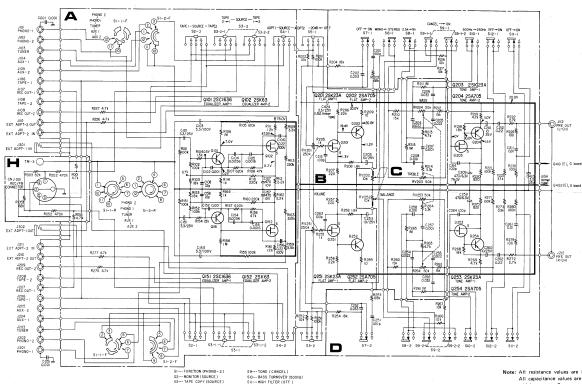


2SK63

2SC1636

TA-4650 TA-4650

3-6. SCHEMATIC DIAGRAM - Preamplifier Section -



SI2--- LOW FILTER (OFF)

Note: All resistance values are in ohms. k = 1,000, M = 1,000 k. All capacitance values are in µF except as indicated with p, which means uuF.

> All voltages are do measured with a VOM which has an input impedance of 20k ohms/volt. No signal in.

> Voltage variations may be noted because of normal production tolerances.

S3--- TAPE COPY (SOURCE)

S4---EXT ADPT (SOURCE)

S8--- TREBLE TURNOVER(2.5kHz)

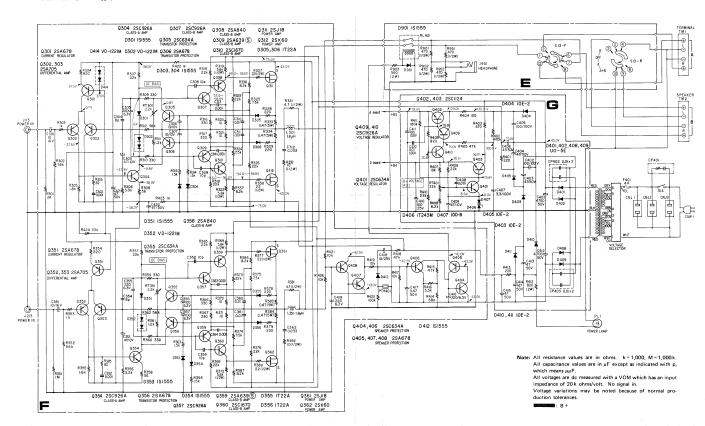
S5---MUTING (OFF)

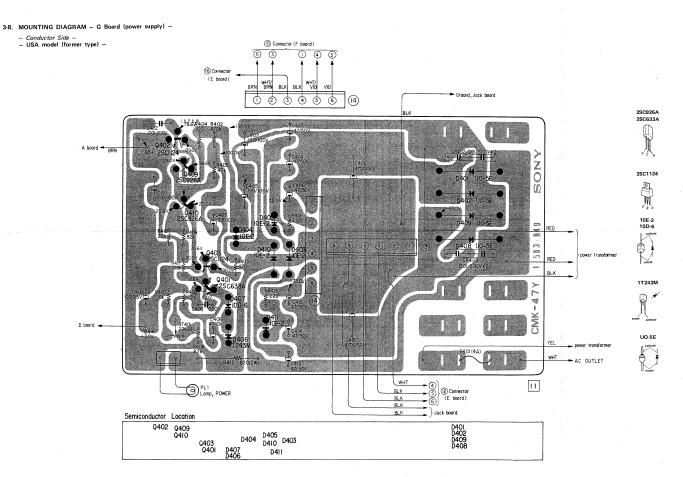
S6--- MODE (STERFO)

S7--- LOUDNESS (OFF)

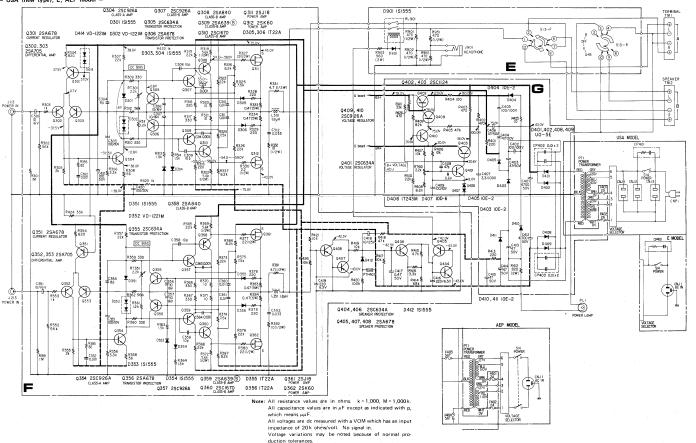
TA-4650 TA-4650

3-7. SCHEMATIC DIAGRAM — Power Amplifier Section — — USA model (former type) —

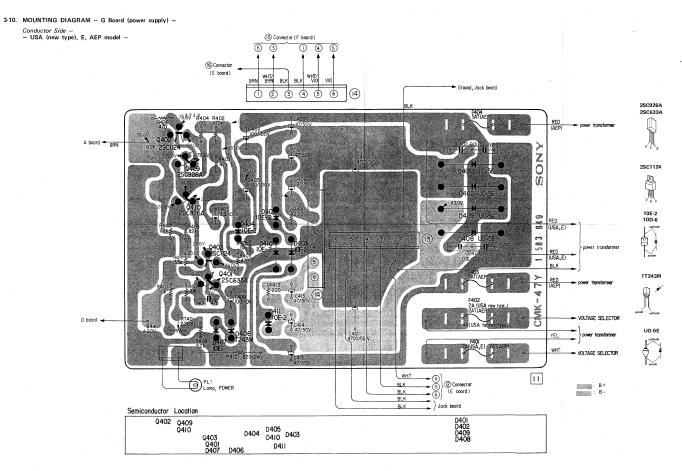




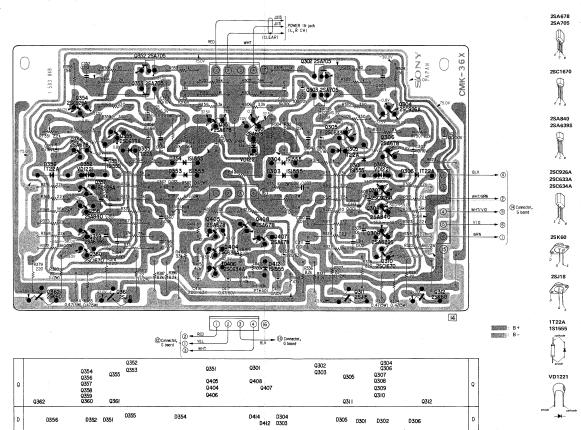
3-9. SCHEMATIC DIAGRAM — Power Amplifier Section — — USA (new type), E, AEP model —



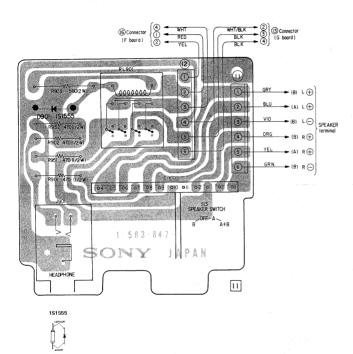
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3-11. MOUNTING DIAGRAM - F Board (power amp) -

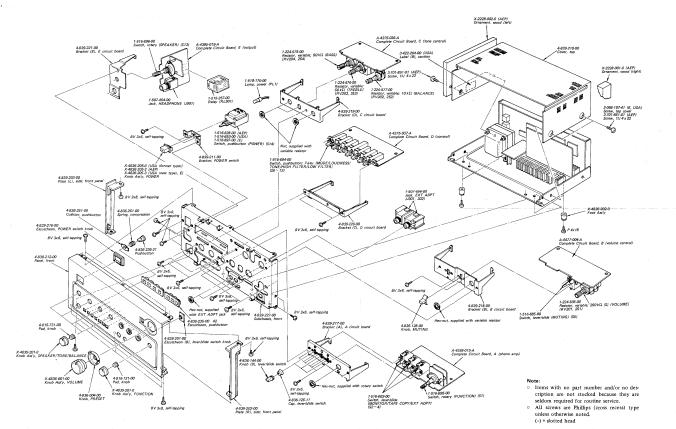


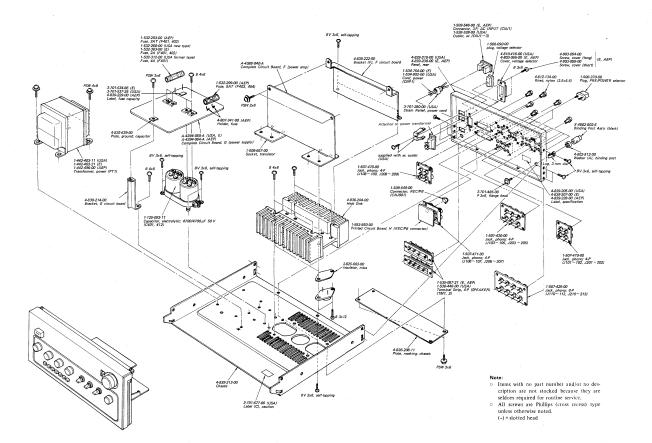
3-12. MOUNTING DIAGRAM — E Board (output) —



MEMO				
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SECTION 5 ELECTRICAL PARTS LIST

Ref. No. Part No.	Description	Ref. No. Part No.	Description	Ref. No. P.	art No.		Description	Ref. No.	Part No.		Description
CIRCII	IT BOARDS	Q404	28C634A	C104(C154) 1-1	05-510-12	0.0056	mylar	C402	1-123-084-11	100	100 V
0,1100	TI BOANDO	Q405	2SA678	C105(C155) 1-1	06-006-12	0.0016	mylar	C403,C404	1-123-058-11	47	50 V
Note: For USA mo	del, former and new B, D, F and G boards	Q406	2SC634A	C106(C156) 1-1	05-729-12	0.22	100 V mylar	C405	1-123-084-11	100	100 V
are interchan	geable respectively.	Q407,Q408	2SA678	C107(C157) 1-1	21-425-11	470	10 V	C406	1-123-058-11	47	50 V
	the state of the s	Q409,Q410	2SC926A								
A-4358-019-A	A (phono amp), complete			C201(C251) 1-1	02-973-11	100 p	ceramic	C407	1-121-995-11	3.3	100 V
A-4477-004-A	B (volume control), complete			C202(C252) 1-1	05-679-12	0.033	mylar		(1-105-661-12	0.001	mylar (USA
A-4375-036-A	C (tone control), complete			C203(C253) 1-1	21-748-11	10	25 V	C408			(former type))
A-4375-037-A	D (control), complete	D	iodes	C204(C254) 1-1	05-677-12	0.022	mylar		1-101-881-11	47 p (U	SA (new type), E, AEP
A-4385-019-A	E (output), complete	1		C205(C255) 1-1	05-677-12	0.022	mylar				model)
A-4388-040-A	F.(power amp), complete	D301(D351)	1S1555						(1-121-352-11	47	10 V (USA (former type))
	G (power supply), complete	D302(D352)	VD1221M	C206(C256) 1-1	05-679-12	0.033	mylar	C409	1-121-414-11	100	10 V (USA (new type), E,
	(USA, E model)	D303(D353)	181555	C207(C257) 1-1	05-661-12	0.001	mylar				AEP model)
A-4394-064-A	G (power supply), complete	D304(D354)	181555	C208(C258) 1-1	05-661-12	0.001	mylar	C410	1-121-935-11	100	25 V (USA (former type))
	(AEP model)	D305(D355)	1T22A	(1-1	21-352-11	47	10 V (USA (former type))	C411	1-123-084-11	100	100 V (USA (former type))
1-583-850-00	H (REC/PB connector)	D306(D356)	1T22A	C209(C259) {1-1	21-424-11	470	6.3 V (USA (new type), E,				, , , , , , , , , , , , , , , , , , ,
							AEP model)	C412	1-125-093-11	4700	50 V
		D401,D402	UO-5E	C210(C260) 1-1	21-748-11	10	25 V	C413~C415	1-123-058-11	47	50 V
	And the second second	D403~D405	10E-2					C416		220	6.3 V
		D406	1T243M	C211(C261) 1-1	05-673-12	0.01	mylar	C417	1-121-726-11	0.47	50 V
SEMICO	INDUCTORS	D407	10D-6	C212(C262) 1-1	05-689-12	0.22	mylar	C418	1-121-398-11	10	25 V
		D408,D409	UO-5E	C213(C263) 1-1	02-973-11	100 p	ceramic				
Tr	ansistors			C214(C264) 1-1	02-973-11	100 p	ceramic	C419	1-121-419-11	220	6.3 V
	A	D410,D411	10E-2						(1-121-411-11	47	50 V (USA (former type))
Q101(Q151)	2SC1636	D412,D413	181555	C301(C351) 1-1	21-916-11	10	16 V	C420,C421	1-121-417-00	100	50 V (USA (new type), E,
Q102(Q152)	2SK63 (FET)	D414	VD1221	C302(C352) 1-1	05-661-12	0.001	mylar				AEP model)
				(1-1	21-352-11	47	10 V (USA (former type))	C423,C424	1-121-392-11	3.3	25 V (USA (former type))
Q201(Q251)	2SK23A (FET)	D901	1S1555	C303(C353)	21-414-11	100	10 V (USA (new type), E,				
Q202(Q252)	2SA705						AEP model)				
Q203(Q253)	2SK23A (FET)			C304(C354) 1-1	02-945-11	8 p	ceramic		RESI	STORS	
Q204(Q254)	2SA705			C305(C355) 1-1	21-419-11	220	6.3 V (USA (former type))				
	and the second second	TRANSFORMER	AND INDUCTORS					All re	esistors are in Ω .	% W, ±5	%, carbon resistors
Q301(Q351)	2SA678			020000000 [1-1	21-413-11	100	6.3 V (USA (former type))		pt special type)		
Q302(Q352)	2SA705	L301(L351) 1-407-592-00	Microinductor, 1.8 µH			10	16 V (USA (new type), E,				ne resistance values.
Q303(Q353)	2SA705	PT1 1-442-403-11	Transformer, power (USA model)				AEP model)	(k = 1	,000, M = 1,000	k)	
Q304(Q354)	2SC926A	1-442-403-21	Transformer, power (E model)		21-413-11	100	6.3 V (USA (former type))				
Q305(Q355)	2SC634A	1-442-496-00	Transformer, power (AEP model)	C307(C357) {1-1	21-651-11	10	16 V (USA (new type), E,	R331(R381)	1-202-517-11	4.7	1/2 W composition
	and the second s						AEP model)		1-202-525-11	1.0	1/2 W composition
Q306(Q356)	2SA678	14		C308(C358) 1-1	02-947-11	10 p	ceramic		1-217-158-11	0.47	5 W metal
Q307(Q357)	2SC926A	CAPA	CITORS	C309(C359) 1-1		10 p	ceramic		1-217-158-11	0.47	5 W metal
Q308(Q358)	2SA840			C310(C360) 1-1		0.01	mylar		,		
Q309(Q359)	2SA639S		electrolytic type unless					R412	1-206-662-11	820	2 W metal-oxide
Q310(Q360)	2SC1670		μμ) The working voltage of 50	C311(C361) 1-1	05-673-12	0.01	mvlar		1-202-565-11	470	½ W composition
	•	volts or less are omit	ted except for electrolytic type.	C312(C362) 1-1		0.033	mylar) 1-202-565-11	470	1/2 W composition
Q311(Q361)	2SJ18 (FET)			C313(C363) 1-1		0.001	mylar	R903	1-206-658-11	560	2 W metal-oxide
Q312(Q362)	2SK60 (FET)	C001(C051) 1-102-074-11	0.001 ceramic	C314(C364) 1-1		0.001	mylar	*****	. 300 000 11		
Q401	2SC634A	C101(C151) 1-121-913-11	3.3 25 V				,	RT301			
Q402,Q403	2SC1124	C102(C152) 1-105-661-12	0.001 mylar	C401 1-1	25-093-11	4700	50 V	(RT351)	1-224-489-00	2.2 k, a	djustable (dc bias adj.)
							· · · · · · · · · · · · · · · · · · ·				

Ref. No	Part No.	Description	Ref. No.	Part No.	Description
RT401	1-224-250-00	2.2 k, adjustable (power voltage adj.)	CNJ1~CN	J3 1-526-528-00	Outlet, ac (USA model)
RV201	1-224-505-00	250 k(S), variable (VOLUME)	CNP1	(1-534-754-00	Cord, power (E model)
(RV251) 1-224-303-00	250 k(S), variable (VOLUME)	CNPI	1-534-992-00	Cord, power (USA model)
(RV202 (RV252	1-224-577-00	10 k, variable (BALANCE)	CP401	1-231-057-31	Encapsulated Component (USA,
RV203	1-224-576-00	50k, variable (TREBLE)			E model)
(RV253 RV204			CP402 CP403	1-102-355-11	Capacitor, ceramic 0.01 µF 500 V
(RV254	1-224-575-00	50 k, variable (BASS)		(1-532-203-00	Fuse, 2AT (AEP model)
			F401.F402		Fuse, 2A (USA model (new type))
			1 401,1 402	1-532-363-00	Fuse, 2A (E model)
	SWI	TCHES	F401	1-532-312-00	Fuse, 4A (USA model (former type))
			F403,F404		Fuse, 5AT (AEP model)
S1	1-516-695-00	Rotary (FUNCTION)	1 405,1 404	1-332-299-00	ruse, 3A1 (AEF model)
S2~S4	1-516-603-00	Lever/Slide (MONITOR.	PL1	1-518-170-00	Lamp, power
		TAPE COPY, EXT ADPT)			***
S5	1-516-685-00	Lever/Slide (MUTING)	Pth401	1-800-340-00	Thermistor (positive)
S6~S12		Pushbutton, 7-key (MODE,	RL901	1-515-257-00	Relay
50 512	131007100	LOUDNESS, TONE, HIGH	TM1,TM2	1-535-057-21	Terminal Strip, 4-P (SPEAKER) (E, AEP model)
S13	1-516-696-00	FILTER, LOW FILTER) Rotary (SPEAKER)		1-536-446-00	Terminal Strip, 4-P (SPEAKER) (USA model)
	1-516-628-00	Pushbutton (POWER) (AEP model)	1.	1-506-370-00	Plug, PRE/POWER selector
S14	1-516-693-00	Pushbutton (POWER) (USA model)	1	1 000 070 00	Tag, TRE/TOWER SERVIOR
	1-516-697-00	Pushbutton (POWER) (E model)		1-508-690-00	Plug, voltage selector (USA model)
				1-509-667-00	Socket, transistor
				1-536-354-00	Pin, terminal
				1-330-354-00	rm, terminai
	JA	ACKS			
J101.J10					
(J201,J2	1-507-470-00	Phone, 4-P			
(J203~J		Phono, 6-P	ACCE	SSORIES AND I	PACKING MATERIALS

ACCESSORIES A	ND PACKING MATERIALS
Part No.	Description
X-3701-029-0	Card Ass'y, warranty
1-506-113-00	Plug, shorting
3-429-126-00	Bag, polyethylene; unit
3-701-020-00	Bag, polyethylene; instruction manual
3-701-730-00	Bag, polyethylene; IBM card
3-701-742-00	Card, IBM
3-780-508-21	Manual, instruction (USA model)
3-780-508-11	Manual, instruction (AEP model)
	Manual, instruction (E model)
3-793-807-11	Schematic Diagram
4-839-225-00	Carton
4-839-226-00	Cushion

Phono, 8-P

J106,J107

(J206,J207) 1-507-471-00 Phono, 4-P (J208,J209) 1-507-470-00 Phono, 4-P

J301,J302 1-507-454-00 EXT ADPT 1-507-454-00 HEADPHONE

(J110~J113 (J210~J213) 1-507-429-00